

- Designed for Complementary Use with the BD244 Series
- 65 W at 25°C Case Temperature
- 6 A Continuous Collector Current
- 10 A Peak Collector Current
- Customer-Specified Selections Available

# 

Pin 2 is in electrical contact with the mounting base.

MDTRACA

# absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT		
	BD243		55		
Collector-emitter voltage ( $R_{BE} = 100 \Omega$ )	BD243A	V	70	v	
	BD243B	V <sub>CER</sub>	90	٧	
	BD243C		115		
	BD243		45		
Collector-emitter voltage (I <sub>C</sub> = 30 mA)	BD243A	V	60	V	
	BD243B	V <sub>CEO</sub>	80		
	BD243C		100		
Emitter-base voltage	V <sub>EBO</sub>	5	V		
Continuous collector current	I <sub>C</sub>	6	Α		
Peak collector current (see Note 1)	I <sub>CM</sub>	10	Α		
Continuous base current			3	Α	
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)			65	W	
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)			2	W	
Unclamped inductive load energy (see Note 4)			62.5	mJ	
Operating junction temperature range			-65 to +150	°C	
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C		
Lead temperature 3.2 mm from case for 10 seconds	T <sub>L</sub>	250	°C		

NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%.$ 

- 2. Derate linearly to 150°C case temperature at the rate of 0.52 W/°C.
- 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.
- 4. This rating is based on the capability of the transistor to operate safely in a circuit of: L = 20 mH,  $I_{B(on)}$  = 0.4 A,  $R_{BE}$  = 100  $\Omega$ ,  $V_{BE(off)}$  = 0,  $R_{S}$  = 0.1  $\Omega$ ,  $V_{CC}$  = 20 V.



# electrical characteristics at 25°C case temperature

PARAMETER			TEST CONDITION	ONS	S MIN			UNIT
V <sub>(BR)CEO</sub>	Collector-emitter breakdown voltage	I <sub>C</sub> = 30 mA (see Note 5)	I <sub>B</sub> = 0	BD243 BD243A BD243B BD243C	45 60 80 100			V
I <sub>CES</sub>	Collector-emitter cut-off current	$V_{CE} = 55 \text{ V}$ $V_{CE} = 70 \text{ V}$ $V_{CE} = 90 \text{ V}$ $V_{CE} = 115 \text{ V}$	$V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$ $V_{BE} = 0$	BD243 BD243A BD243B BD243C			0.4 0.4 0.4 0.4	mA
I <sub>CEO</sub>	Collector cut-off current	V <sub>CE</sub> = 30 V V <sub>CE</sub> = 60 V	I <sub>B</sub> = 0 I <sub>B</sub> = 0	BD243/243A BD243B/243C			0.7 0.7	mA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 5 V	I <sub>C</sub> = 0				1	mA
h <sub>FE</sub>	Forward current transfer ratio	$V_{CE} = 4 V$ $V_{CE} = 4 V$	$I_C = 0.3 A$ $I_C = 3 A$	(see Notes 5 and 6)	30 15			
V <sub>CE(sat)</sub>	Collector-emitter saturation voltage	I <sub>B</sub> = 1 A	I <sub>C</sub> = 6 A	(see Notes 5 and 6)			1.5	٧
$V_{BE}$	Base-emitter voltage	V <sub>CE</sub> = 4 V	I <sub>C</sub> = 6 A	(see Notes 5 and 6)			2	٧
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 kHz	20			
h <sub>fe</sub>	Small signal forward current transfer ratio	V <sub>CE</sub> = 10 V	I <sub>C</sub> = 0.5 A	f = 1 MHz	3			

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu s$ , duty cycle  $\leq 2\%$ .

# thermal characteristics

PARAMETER			TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.92	°C/W
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	°C/W

# resistive-load-switching characteristics at 25°C case temperature

	PARAMETER	TEST CONDITIONS †			MIN	TYP	MAX	UNIT
t <sub>on</sub>	Turn-on time	I <sub>C</sub> = 1 A	$I_{B(on)} = 0.1 A$	$I_{B(off)} = -0.1 A$		0.3		μs
t <sub>off</sub>	Turn-off time	$V_{BE(off)} = -3.7 \text{ V}$	$R_L = 20 \Omega$	$t_p = 20 \ \mu s, \ dc \le 2\%$		1		μs

<sup>&</sup>lt;sup>†</sup> Voltage and current values shown are nominal; exact values vary slightly with transistor parameters.

<sup>6.</sup> These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### **TYPICAL CHARACTERISTICS**

# **TYPICAL DC CURRENT GAIN** vs **COLLECTOR CURRENT** TCS633AH 1000 $V_{CE} = 4 V$ $T_{\rm C} = 25^{\circ}{\rm C}$ $t_p = 300 \mu s$ , duty cycle < 2%h<sub>FE</sub> - DC Current Gain 100 10 1.0 0.1 1.0 10 I<sub>c</sub> - Collector Current - A

Figure 1.

### **COLLECTOR-EMITTER SATURATION VOLTAGE**

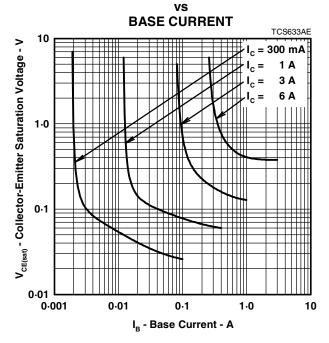
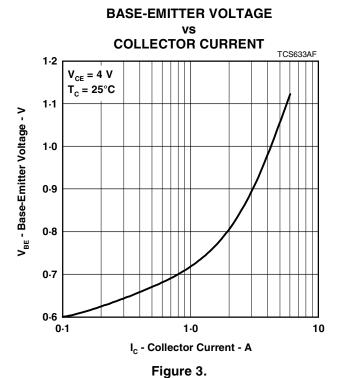
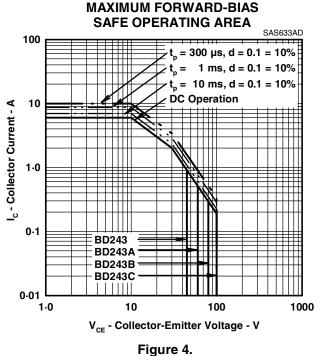


Figure 2.



### PRODUCT INFORMATION

### **MAXIMUM SAFE OPERATING REGIONS**



### THERMAL INFORMATION

# **MAXIMUM POWER DISSIPATION**

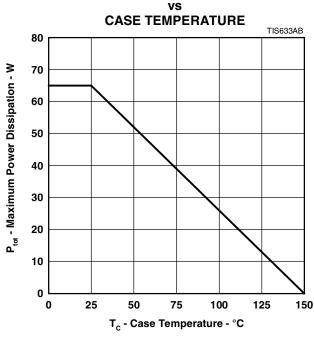


Figure 5.

### PRODUCT INFORMATION